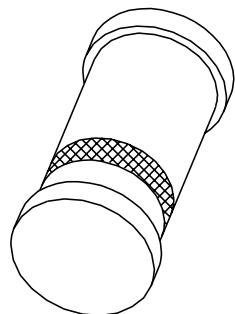


# **DATA SHEET**



## **BAV100 to BAV103**

### **General purpose diodes**

Product specification  
Supersedes data of April 1996

1996 Sep 17

## General purpose diodes

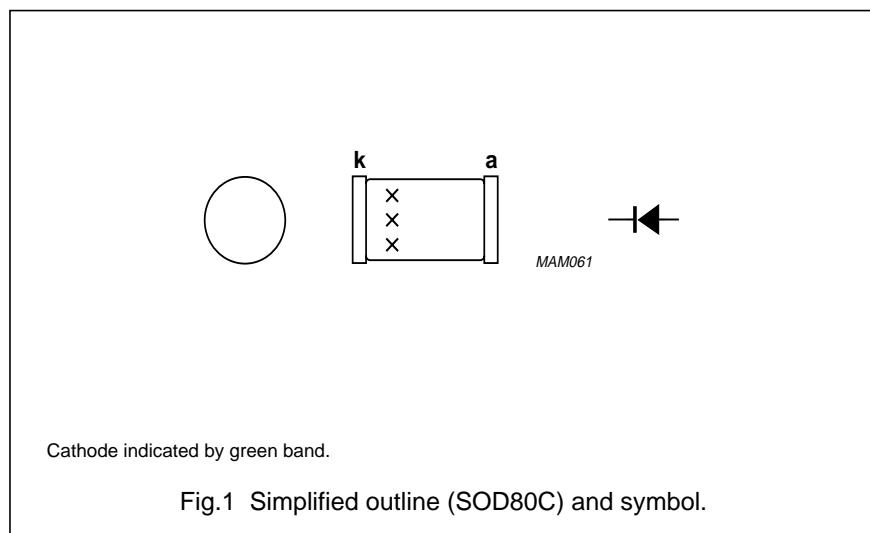
## BAV100 to BAV103

### FEATURES

- Small hermetically sealed glass SMD package
- Switching speed: max. 50 ns
- General application
- Continuous reverse voltage: max. 50 V, 100 V, 150 V and 200 V respectively
- Repetitive peak reverse voltage: max. 60 V, 120 V, 200 V and 250 V respectively
- Repetitive peak forward current: max. 625 mA.

### DESCRIPTION

The BAV100 to BAV103 are switching diodes fabricated in planar technology, and encapsulated in small hermetically sealed glass SOD80C SMD packages.



### APPLICATIONS

- Switching in industrial equipment e.g. oscilloscopes, digital voltmeters and video output stages in colour television.

## General purpose diodes

## BAV100 to BAV103

**LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL    | PARAMETER   | CONDITIONS   | MIN. | MAX.        | UNIT |
|-----------|---|--|------|-------------|------|
| $V_{RRM}$ | repetitive peak reverse voltage<br>BAV100<br>BAV101<br>BAV102<br>BAV103 |  | —    | 60          | V    |
| $V_R$     | continuous reverse voltage<br>BAV100<br>BAV101<br>BAV102<br>BAV103      |  | —    | 120         | V    |
| $I_F$     | continuous forward current  | see Fig.2; note 1  | —    | 200         | mA   |
| $I_{FRM}$ | repetitive peak forward current   |  | —    | 625         | mA   |
| $I_{FSM}$ | non-repetitive peak forward current                                     | square wave; $T_j = 25^\circ\text{C}$ prior to surge; see Fig.4<br>$t = 1 \mu\text{s}$<br>$t = 100 \mu\text{s}$<br>$t = 1 \text{ s}$ |      | 9<br>3<br>1 | A    |
| $P_{tot}$ | total power dissipation   | $T_{amb} = 25^\circ\text{C}$ ; note 1  | —    | 400         | mW   |
| $T_{stg}$ | storage temperature   |  | -65  | +175        | °C   |
| $T_j$     | junction temperature  |  | —    | 175         | °C   |

**Note**

1. Device mounted on an FR4 printed-circuit board.

## General purpose diodes

## BAV100 to BAV103

**ELECTRICAL CHARACTERISTICS** $T_j = 25^\circ\text{C}$ ; unless otherwise specified.

| SYMBOL   | PARAMETER   | CONDITIONS  | MIN.                                 | MAX.   | UNIT   |
|----------|---|---|--------------------------------------|--|--|
| $V_F$    | forward voltage   | see Fig.3<br>$I_F = 100 \text{ mA}$<br>$I_F = 200 \text{ mA}$   | —                                    | 1.0<br>1.25  | V<br>V   |
| $I_R$    | reverse current<br>BAV100<br>BAV101<br>BAV102<br>BAV103 | see Fig.5<br>$V_R = 50 \text{ V}$<br>$V_R = 50 \text{ V}; T_j = 150^\circ\text{C}$<br>$V_R = 100 \text{ V}$<br>$V_R = 100 \text{ V}; T_j = 150^\circ\text{C}$<br>$V_R = 150 \text{ V}$<br>$V_R = 150 \text{ V}; T_j = 150^\circ\text{C}$<br>$V_R = 200 \text{ V}$<br>$V_R = 200 \text{ V}; T_j = 150^\circ\text{C}$ | —<br>—<br>—<br>—<br>—<br>—<br>—<br>— | 100<br>100<br>100<br>100<br>100<br>100<br>100<br>100 | nA<br>$\mu\text{A}$<br>nA<br>$\mu\text{A}$<br>nA<br>$\mu\text{A}$<br>nA<br>$\mu\text{A}$ |
| $C_d$    | diode capacitance                                       | $f = 1 \text{ MHz}; V_R = 0$ ; see Fig.6  | —                                    | 5  | pF   |
| $t_{rr}$ | reverse recovery time                                   | when switched from $I_F = 30 \text{ mA}$ to $I_R = 30 \text{ mA}$ ; $R_L = 100 \Omega$ ; measured at $I_R = 3 \text{ mA}$ ; see Fig.8   | —                                    | 50   | ns   |

**THERMAL CHARACTERISTICS**

| SYMBOL        | PARAMETER                                     | CONDITIONS | VALUE | UNIT |
|---------------|---|------------|-------|------|
| $R_{th j-tp}$ | thermal resistance from junction to tie-point |            | 300   | K/W  |
| $R_{th j-a}$  | thermal resistance from junction to ambient   | note 1     | 375   | K/W  |

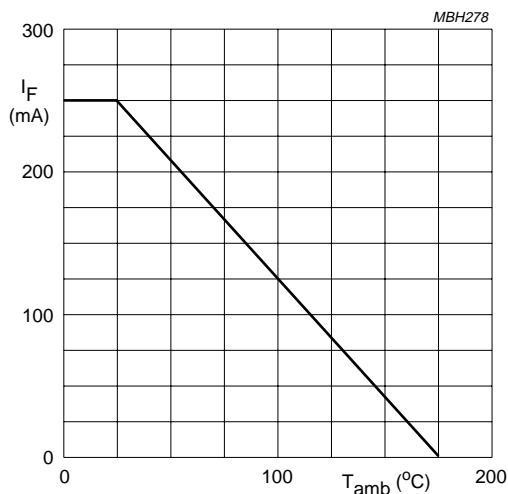
**Note**

1. Device mounted on an FR4 printed-circuit board.

## General purpose diodes

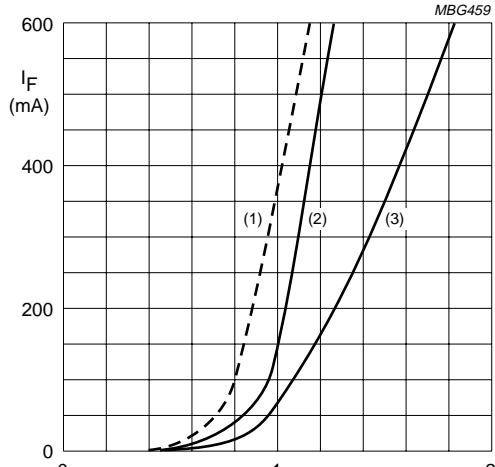
## BAV100 to BAV103

## GRAPHICAL DATA



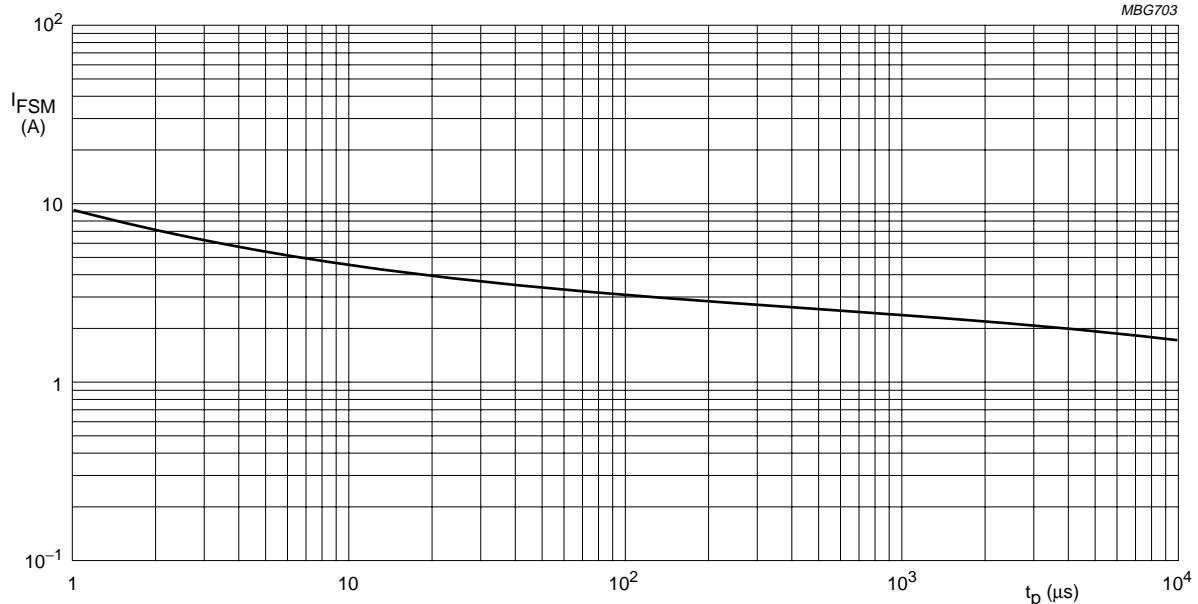
Device mounted on an FR4 printed-circuit board.

Fig.2 Maximum permissible continuous forward current as a function of ambient temperature.



- (1)  $T_j = 150 \text{ }^\circ\text{C}$ ; typical values.
- (2)  $T_j = 25 \text{ }^\circ\text{C}$ ; typical values.
- (3)  $T_j = 25 \text{ }^\circ\text{C}$ ; maximum values.

Fig.3 Forward current as a function of forward voltage.



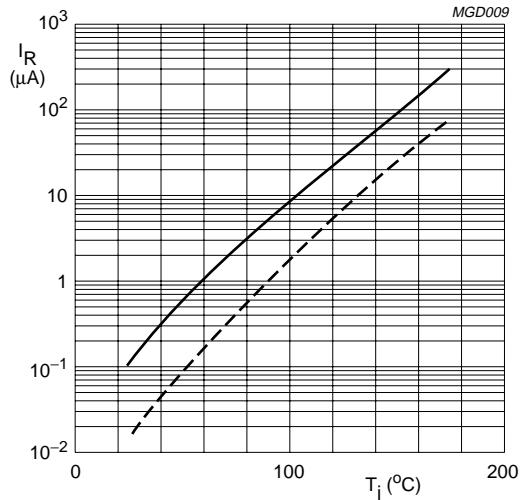
Based on square wave currents.

$T_j = 25 \text{ }^\circ\text{C}$  prior to surge.

Fig.4 Maximum permissible non-repetitive peak forward current as a function of pulse duration.

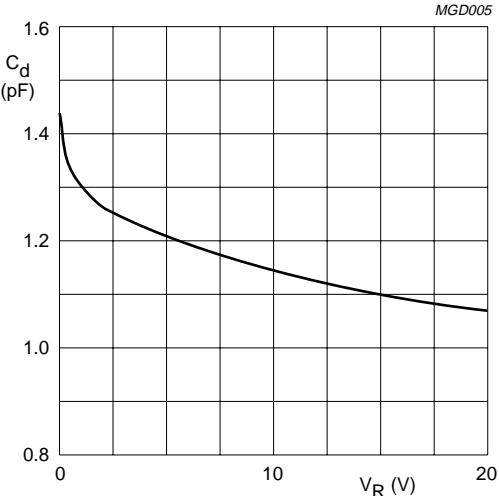
## General purpose diodes

## BAV100 to BAV103



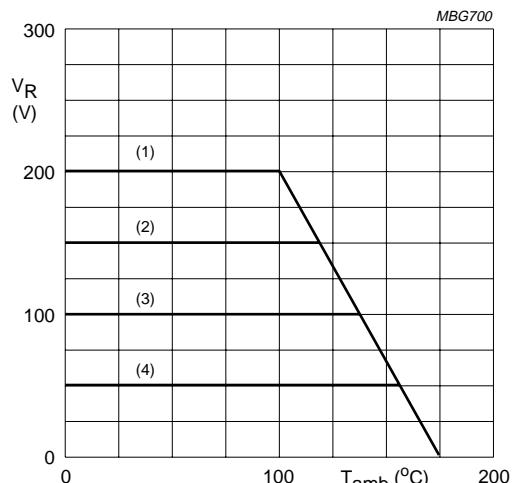
$V_R = V_{R\max}$ .  
Solid line; maximum values.  
Dotted line; typical values.

Fig.5 Reverse current as a function of junction temperature.



$f = 1 \text{ MHz}; T_j = 25 \text{ }^\circ\text{C}$ .

Fig.6 Diode capacitance as a function of reverse voltage; typical values.



- (1) BAV103.
- (2) BAV102.
- (3) BAV101.
- (4) BAV100.

Fig.7 Maximum permissible continuous reverse voltage as a function of ambient temperature.

## General purpose diodes

## BAV100 to BAV103

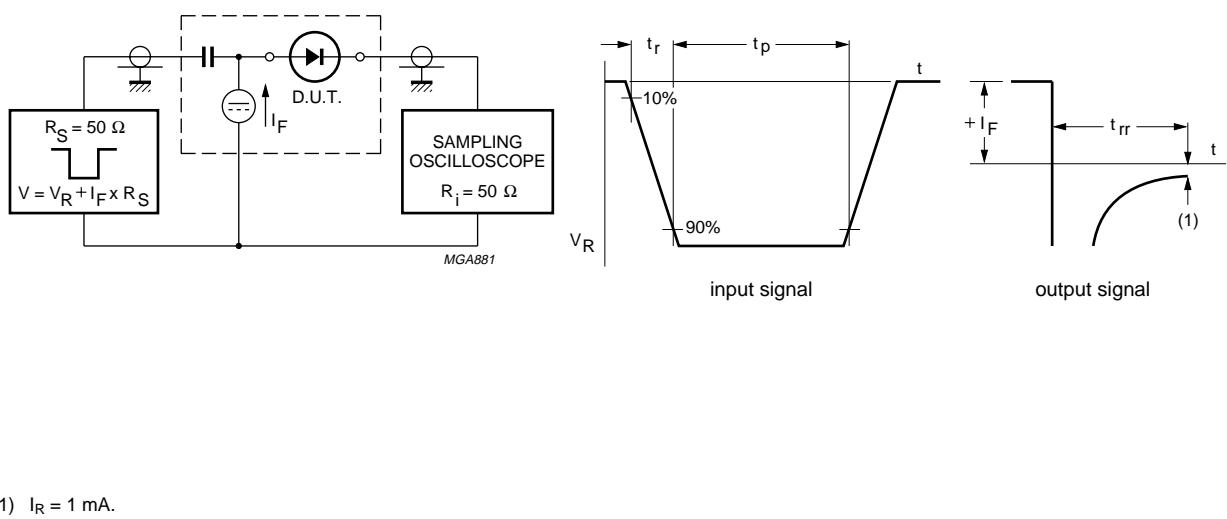
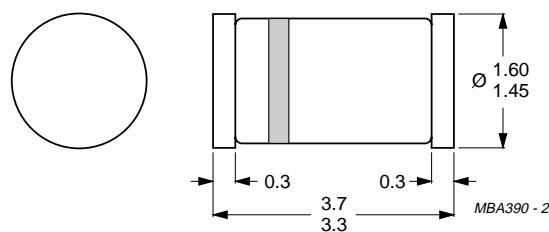


Fig.8 Reverse recovery voltage test circuit and waveforms.

## General purpose diodes

BAV100 to BAV103

## PACKAGE OUTLINE



Dimensions in mm.

Fig.9 SOD80C.

## DEFINITIONS

| <b>Data Sheet Status</b>  |   |
|---|---|
| Objective specification   | This data sheet contains target or goal specifications for product development.       |
| Preliminary specification   | This data sheet contains preliminary data; supplementary data may be published later. |
| Product specification   | This data sheet contains final product specifications.                                |
| <b>Limiting values</b>  |   |
| Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability. |   |
| <b>Application information</b>  |   |
| Where application information is given, it is advisory and does not form part of the specification.   |   |

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